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1. General description

The 74LV4051 is an 8-channel analog multiplexer/demultiplexer with three digital select inputs (S0 to S2), an active-LOW enable input (\overline{E}), eight independent inputs/outputs (Y0 to Y7) and a common input/output (Z). It is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC4051 and 74HCT4051. With \overline{E} LOW, one of the eight switches is selected (low impedance ON-state) by S0 to S2. With \overline{E} HIGH, all switches are in the high-impedance OFF-state, independent of S0 to S2.

 V_{CC} and GND are the supply voltage pins for the digital control inputs (S0 to S2, and \overline{E}). The V_{CC} to GND ranges are 1.0 V to 6.0 V. The analog inputs/outputs (Y0 to Y7, and Z) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. $V_{CC} - V_{EE}$ may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

2. Features and benefits

- Optimized for low-voltage applications: 1.0 V to 6.0 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Low ON resistance:
 - 145 Ω (typical) at V_{CC} V_{EE} = 2.0 V
 - 80 Ω (typical) at V_{CC} V_{EE} = 3.0 V
 - 60 Ω (typical) at V_{CC} V_{EE} = 4.5 V
- Logic level translation:
 - ◆ To enable 3 V logic to communicate with ±3 V analog signals
- Typical 'break before make' built in
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C



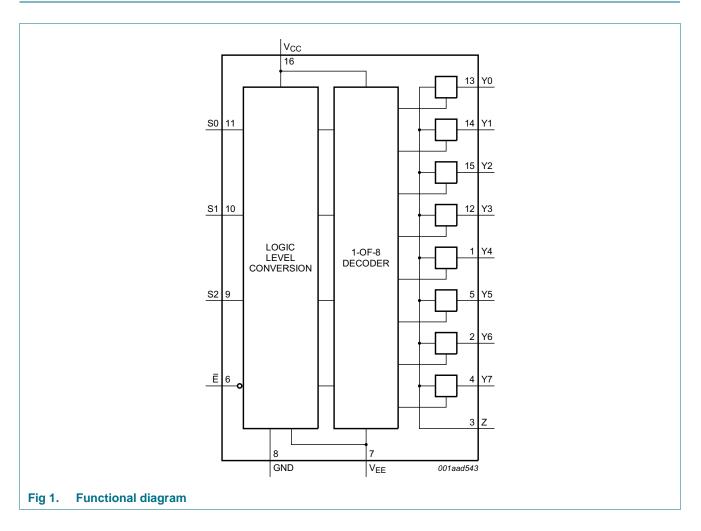
8-channel analog multiplexer/demultiplexer

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | |
|-------------|-------------------|----------|--|----------|
| | Temperature range | Name | Description | Version |
| 74LV4051D | –40 °C to +125 °C | SO16 | plastic small outline package; 16 leads; body width 3.9 mm | SOT109-1 |
| 74LV4051DB | –40 °C to +125 °C | SSOP16 | plastic shrink small outline package; 16 leads; body width 5.3 mm | SOT338-1 |
| 74LV4051PW | –40 °C to +125 °C | TSSOP16 | plastic thin shrink small outline package; 16 leads; body width 4.4 mm | SOT403-1 |
| 74LV4051BQ | –40 °C to +125 °C | DHVQFN16 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm | SOT763-1 |

4. Functional diagram

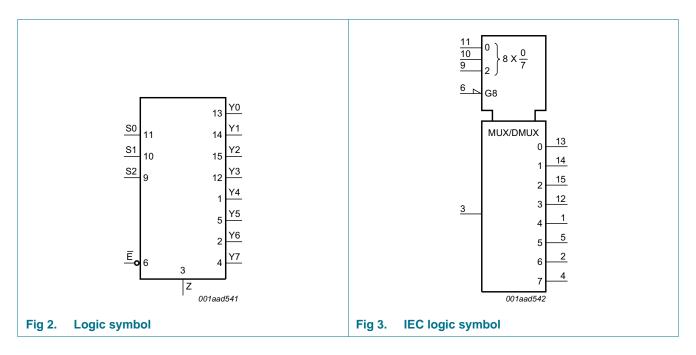


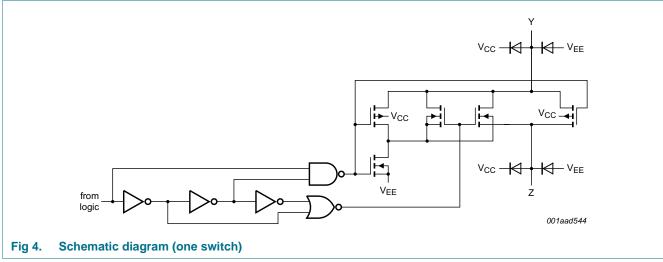
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NXP Semiconductors

74LV4051

8-channel analog multiplexer/demultiplexer

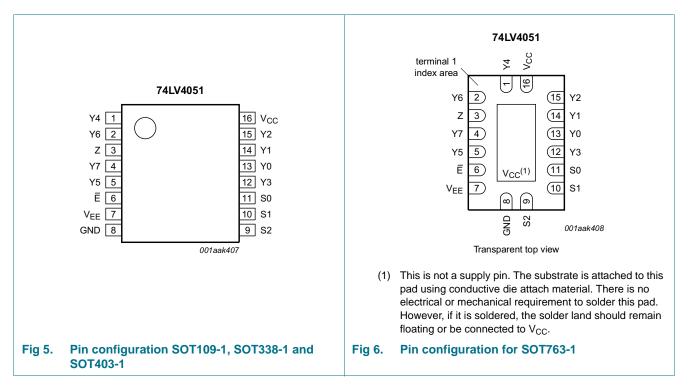




8-channel analog multiplexer/demultiplexer

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|--------------------------------|----------------------------|-----------------------------|
| Ē | 6 | enable input (active LOW) |
| V _{EE} | 7 | supply voltage |
| GND | 8 | ground supply voltage |
| S0, S1, S2 | 11, 10, 9 | select input |
| Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7 | 13, 14, 15, 12, 1, 5, 2, 4 | independent input or output |
| Z | 3 | common output or input |
| V _{CC} | 16 | supply voltage |

8-channel analog multiplexer/demultiplexer

6. Functional description

6.1 Function table

 Table 3.
 Function table^[1]

| Input | | | | Channel ON |
|-------|----|----|----|--------------|
| Ē | S2 | S1 | S0 | |
| L | L | L | L | Y0 to Z |
| L | L | L | Н | Y1 to Z |
| L | L | Н | L | Y2 to Z |
| L | L | Н | Н | Y3 to Z |
| L | Н | L | L | Y4 to Z |
| L | Н | L | Н | Y5 to Z |
| L | Н | Н | L | Y6 to Z |
| L | Н | Н | Н | Y7 to Z |
| Н | Х | Х | Х | switches off |

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

| Symbol | Parameter | Conditions | | Min | Max | Unit | | |
|------------------|-------------------------|---|------------|------|------|------|--|--|
| V _{CC} | supply voltage | | <u>[1]</u> | -0.5 | +7.0 | V | | |
| I _{IK} | input clamping current | $V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V | [2] | - | ±20 | mA | | |
| I _{SK} | switch clamping current | V_{SW} < –0.5 V or V_{SW} > V_{CC} + 0.5 V | [2] | - | ±20 | mA | | |
| I _{SW} | switch current | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current | <u>[2]</u> | - | ±25 | mA | | |
| T _{stg} | storage temperature | | | -65 | +150 | °C | | |
| P _{tot} | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ | <u>[3]</u> | | | | | |
| | | SO16 package | | - | 500 | mW | | |
| | | TSSOP16 package | | - | 500 | mW | | |
| | | DHVQFN16 package | | - | 500 | mW | | |
| | | | | | | | | |

[1] To avoid drawing V_{CC} current out of terminal Z, when switch current flows into terminals Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Yn, and in this case there is no limit for the voltage drop across the switch, but the voltages at Yn and Z may not exceed V_{CC} or V_{EE} .

[2] The minimum input voltage rating may be exceeded if the input current rating is observed.

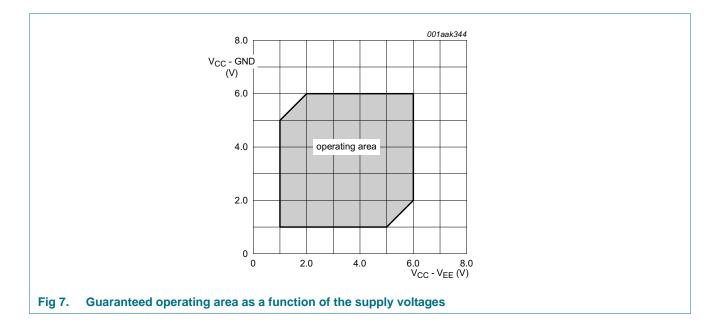
[3] For SO16 packages: above 70 °C the value of P_{tot} derates linearly with 8 mW/K. For SSOP16 and TSSOP16 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K. For DHVQFN16 packages: above 60 °C the value of P_{tot} derates linearly with 4.5 mW/K.

8-channel analog multiplexer/demultiplexer

Recommended operating conditions 8.

| Table 5. | able 5. Recommended operating conditions ^[1] | | | | | | | | | | |
|-----------------------|---|--|-----|-----|-----------------|------|--|--|--|--|--|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | | | | | |
| V _{CC} | supply voltage | see Figure 7 | 1 | 3.3 | 6 | V | | | | | |
| VI | input voltage | | 0 | - | V _{CC} | V | | | | | |
| V _{SW} | switch voltage | | 0 | - | V _{CC} | V | | | | | |
| T _{amb} | ambient temperature | in free air | -40 | - | +125 | °C | | | | | |
| $\Delta t / \Delta V$ | input transition rise and fall rate | $V_{CC} = 1.0 \text{ V} \text{ to } 2.0 \text{ V}$ | - | - | 500 | ns/V | | | | | |
| | | $V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$ | - | - | 200 | ns/V | | | | | |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 100 | ns/V | | | | | |

[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to 6.0 V, but LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).



8-channel analog multiplexer/demultiplexer

9. Static characteristics

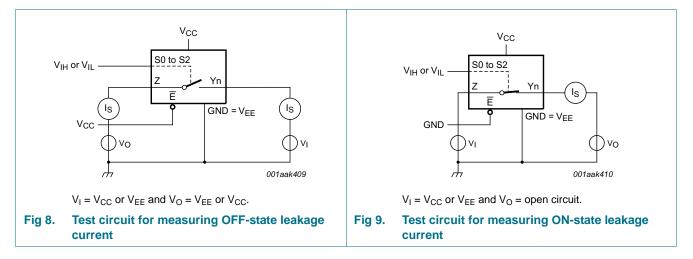
Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | -40 | °C to +8 | S °C | –40 °C to | Unit | |
|------------------|---------------------------|--|------|----------|------|-----------|------|----|
| | | | Min | Typ[1] | Max | Min | Max | |
| VIH | HIGH-level input voltage | V _{CC} = 1.2 V | 0.9 | - | - | 0.9 | - | V |
| | | V _{CC} = 2.0 V | 1.4 | - | - | 1.4 | - | V |
| | | V_{CC} = 2.7 V to 3.6 V | 2.0 | - | - | 2.0 | - | V |
| | | V _{CC} = 4.5 V | 3.15 | - | - | 3.15 | - | V |
| | | V _{CC} = 6.0 V | 4.20 | - | - | 4.20 | - | V |
| VIL | LOW-level input voltage | V _{CC} = 1.2 V | - | - | 0.3 | - | 0.3 | V |
| | | V _{CC} = 2.0 V | - | - | 0.6 | - | 0.6 | V |
| | | V _{CC} = 2.7 V to 3.6 V | - | - | 0.8 | - | 0.8 | V |
| | | V _{CC} = 4.5 V | - | - | 1.35 | - | 1.35 | V |
| | | V _{CC} = 6.0 V | - | - | 1.80 | - | 1.80 | V |
| 1 | input leakage current | $V_I = V_{CC}$ or GND | | | | | | |
| | | V _{CC} = 3.6 V | - | - | 1.0 | - | 1.0 | μΑ |
| | | V _{CC} = 6.0 V | - | - | 2.0 | - | 2.0 | μΑ |
| S(OFF) | OFF-state leakage current | $V_I = V_{IH}$ or V_{IL} ; see Figure 8 | | | | | | |
| | | V _{CC} = 3.6 V | - | - | 1.0 | - | 1.0 | μΑ |
| | | V _{CC} = 6.0 V | - | - | 2.0 | - | 2.0 | μΑ |
| S(ON) | ON-state leakage current | $V_I = V_{IH}$ or V_{IL} ; see Figure 9 | | | | | | |
| | | V _{CC} = 3.6 V | - | - | 1.0 | - | 1.0 | μΑ |
| | | V _{CC} = 6.0 V | - | - | 2.0 | - | 2.0 | μΑ |
| lcc | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A | | | | | | |
| | | V _{CC} = 3.6 V | - | - | 20 | - | 40 | μΑ |
| | | V _{CC} = 6.0 V | - | - | 40 | - | 80 | μΑ |
| ∆l _{CC} | additional supply current | per input; V _I = V _{CC} – 0.6 V; V _{CC} = 2.7 V to 3.6 V | - | - | 500 | - | 850 | μA |
| CI | input capacitance | | - | 3.5 | - | - | - | pF |
| C _{sw} | switch capacitance | independent pins Yn | - | 5 | - | - | - | pF |
| | | common pin Z | - | 25 | - | - | - | pF |

[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

8-channel analog multiplexer/demultiplexer



9.1 Test circuits

9.2 ON resistance

Table 7. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 10</u> and <u>Figure 11</u>.

| Symbol | Parameter | Conditions | -40 | °C to +8 | 5 °C | -40 °C t | o +125 °C | Unit |
|-----------------------|------------------------|--|-----|----------------------|------|----------|-----------|------|
| | | | Min | Typ <mark>[1]</mark> | Max | Min | Max | - |
| R _{ON(peak)} | ON resistance (peak) | $V_I = 0 V \text{ to } V_{CC} - V_{EE}$ | | | | | | |
| | | $V_{CC} = 1.2 \text{ V}; \text{ I}_{SW} = 100 \mu\text{A}$ [2] | - | - | - | - | - | Ω |
| | | $V_{CC} = 2.0 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 145 | 325 | - | 375 | Ω |
| | | $V_{CC} = 2.7 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 90 | 200 | - | 235 | Ω |
| | - | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$ | - | 80 | 180 | - | 210 | Ω |
| | | $V_{CC} = 4.5 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 60 | 135 | - | 160 | Ω |
| | | $V_{CC} = 6.0 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 55 | 125 | - | 145 | Ω |
| ΔR_{ON} | ON resistance mismatch | $V_I = 0 V \text{ to } V_{CC} - V_{EE}$ | | | | | | |
| | between channels | $V_{CC} = 1.2 \text{ V}; \text{ I}_{SW} = 100 \mu\text{A}$ [2] | - | - | - | - | - | Ω |
| | | $V_{CC} = 2.0 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 5 | - | - | - | Ω |
| | | $V_{CC} = 2.7 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 4 | - | - | - | Ω |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$ | - | 4 | - | - | - | Ω |
| | | $V_{CC} = 4.5 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 3 | - | - | - | Ω |
| | | $V_{CC} = 6.0 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 2 | - | - | - | Ω |

8-channel analog multiplexer/demultiplexer

Table 7. ON resistance ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 10</u> and <u>Figure 11</u>.

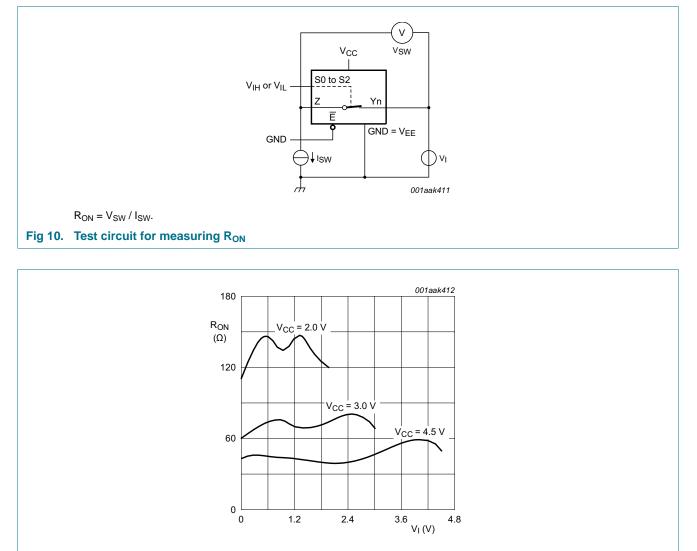
| Symbol | Parameter | Conditions | -40 | °C to +8 | 5 °C | -40 °C to | Unit | |
|-----------------------|----------------------|---|-----|----------------------|------|-----------|------|---|
| | | | Min | Typ <mark>[1]</mark> | Max | Min | Max | |
| R _{ON(rail)} | ON resistance (rail) | V _I = GND | | | | | | |
| | | $V_{CC} = 1.2 \text{ V}; \text{ I}_{SW} = 100 \mu\text{A}$ [2] | - | 225 | - | - | - | Ω |
| | | V_{CC} = 2.0 V; I_{SW} = 1000 μ A | - | 110 | 235 | - | 270 | Ω |
| | | V_{CC} = 2.7 V; I_{SW} = 1000 μ A | - | 70 | 145 | - | 165 | Ω |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$ | - | 60 | 130 | - | 150 | Ω |
| | | V_{CC} = 4.5 V; I_{SW} = 1000 μ A | - | 45 | 100 | - | 115 | Ω |
| | | $V_{CC} = 6.0 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 40 | 85 | - | 100 | Ω |
| R _{ON(rail)} | ON resistance (rail) | $V_I = V_{CC} - V_{EE}$ | | | | | | |
| | | $V_{CC} = 1.2 \text{ V}; \text{ I}_{SW} = 100 \mu\text{A}$ [2] | - | 250 | - | - | - | Ω |
| | | V_{CC} = 2.0 V; I_{SW} = 1000 μ A | - | 120 | 320 | - | 370 | Ω |
| | | V_{CC} = 2.7 V; I_{SW} = 1000 μ A | - | 75 | 195 | - | 225 | Ω |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$ | - | 70 | 175 | - | 205 | Ω |
| | | V_{CC} = 4.5 V; I _{SW} = 1000 µA | - | 50 | 130 | - | 150 | Ω |
| | | $V_{CC} = 6.0 \text{ V}; \text{ I}_{SW} = 1000 \mu\text{A}$ | - | 45 | 120 | - | 135 | Ω |

[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

[2] When supply voltages (V_{CC} – V_{EE}) near 1.2 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 1.2 V, it is recommended to use these devices only for transmitting digital signals.

8-channel analog multiplexer/demultiplexer

9.3 On resistance waveform and test circuit



 V_i = 0 V to $V_{CC}-V_{EE}$



8-channel analog multiplexer/demultiplexer

10. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 14.

| Symbol | Parameter | Conditions | | -40 | °C to +85 | 5 °C | _40 °C t | Unit | |
|-----------------|-------------------|--|-----|-----|----------------------|------|----------|------|----|
| | | | | Min | Typ <mark>[1]</mark> | Max | Min | Max | |
| t _{pd} | propagation delay | Yn to Z, Z to Yn; see Figure 12 | [2] | | | | | | |
| | | V _{CC} = 1.2 V | | - | 25 | - | - | - | ns |
| | | V _{CC} = 2.0 V | | - | 9 | 17 | - | 20 | ns |
| | | V _{CC} = 2.7 V | | - | 6 | 13 | - | 15 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | [3] | - | 5 | 10 | - | 12 | ns |
| | | V _{CC} = 4.5 V | | - | 4 | 9 | - | 10 | ns |
| | | V _{CC} = 6.0 V | | - | 3 | 8 | - | 8 | ns |
| t _{en} | enable time | E to Yn, Z; see Figure 13 | [2] | | | | | | |
| | | V _{CC} = 1.2 V | | - | 145 | - | - | - | ns |
| | | V _{CC} = 2.0 V | | - | 49 | 94 | - | 112 | ns |
| | | V _{CC} = 2.7 V | | - | 36 | 69 | - | 83 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_{L} = 15 \text{ pF}$ | [3] | - | 23 | - | - | - | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | [3] | - | 28 | 55 | - | 66 | ns |
| | | V _{CC} = 4.5 V | | - | 25 | 47 | - | 56 | ns |
| | | $V_{CC} = 6.0 V$ | | - | 19 | 38 | - | 43 | ns |
| | | Sn to Yn; see Figure 13 | [2] | | | | | | |
| | | V _{CC} = 1.2 V | | - | 140 | - | - | - | ns |
| | | $V_{CC} = 2.0 V$ | | - | 48 | 90 | - | 107 | ns |
| | | V _{CC} = 2.7 V | | - | 35 | 66 | - | 79 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_{L} = 15 \text{ pF}$ | [3] | - | 22 | - | - | - | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | [3] | - | 27 | 53 | - | 63 | ns |
| | | V _{CC} = 4.5 V | | - | 24 | 45 | - | 54 | ns |
| | | V _{CC} = 6.0 V | | - | 18 | 34 | - | 41 | ns |

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8-channel analog multiplexer/demultiplexer

| Symbol | Parameter | Conditions | | -40 | °C to +85 | o °C | –40 °C t | o +125 °C | Unit |
|------------------|----------------------------------|--|-----------|-----|----------------------|------|----------|-----------|------|
| | | | | Min | Typ <mark>[1]</mark> | Max | Min | Max | |
| t _{dis} | disable time | E to Yn, Z; see Figure 13 | 2] | | | | | | |
| | | V _{CC} = 1.2 V | | - | 145 | - | - | - | ns |
| | | V _{CC} = 2.0 V | | - | 51 | 93 | - | 110 | ns |
| | | V _{CC} = 2.7 V | | - | 38 | 69 | - | 82 | ns |
| | | $V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}; C_L = 15 \text{ pF}$ | 3] | - | 25 | - | - | - | ns |
| | V _{CC} = 3.0 V to 3.6 V | 3] | - | 30 | 56 | - | 66 | ns | |
| | | V _{CC} = 4.5 V | | - | 29 | 48 | - | 56 | ns |
| | | V _{CC} = 6.0 V | | - | 21 | 37 | - | 44 | ns |
| | | Sn to Yn; see Figure 13 | 2] | | | | | | |
| | | V _{CC} = 1.2 V | | - | 115 | - | - | - | ns |
| | | V _{CC} = 2.0 V | | - | 41 | 73 | - | 90 | ns |
| | | V _{CC} = 2.7 V | | - | 31 | 54 | - | 67 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_{L} = 15 \text{ pF}$ | 3] | - | 20 | - | - | - | ns |
| | | $V_{\rm CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 3] | - | 24 | 44 | - | 54 | ns |
| | | V _{CC} = 4.5 V | | - | 22 | 37 | - | 46 | ns |
| | | V _{CC} = 6.0 V | | - | 17 | 29 | - | 36 | ns |
| C _{PD} | power dissipation capacitance | $\label{eq:CL} \begin{split} &C_L = 50 \text{ pF; } f_i = 1 \text{ MHz;} \\ &V_I = \text{GND to } V_{\text{CC}} \end{split}$ | <u>4]</u> | - | 25 | - | - | - | pF |

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 14.

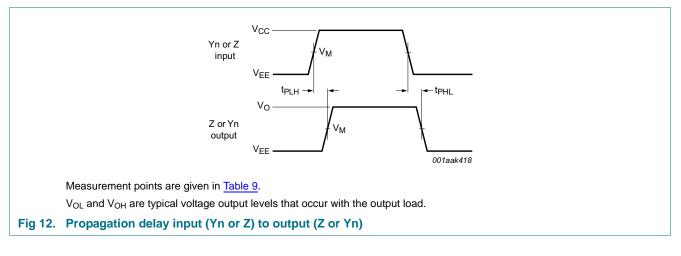
[1] All typical values are measured at T_{amb} = 25 °C.

- [3] Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$).
- $\begin{array}{ll} \mbox{[4]} & C_{PD} \mbox{ is used to determine the dynamic power dissipation (P_D in μW). } \\ & P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma((C_L + C_{SW}) \times V_{CC}{}^2 \times f_o) \mbox{ where:} \\ & f_i = \mbox{ input frequency in MHz, } f_o = \mbox{ output frequency in MHz} \\ & C_L = \mbox{ output load capacitance in } pF \\ & C_{SW} = \mbox{ maximum switch capacitance in } pF; \\ & V_{CC} = \mbox{ supply voltage in Volts} \\ & N = \mbox{ number of inputs switching} \end{array}$

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs.

8-channel analog multiplexer/demultiplexer

10.1 Waveforms



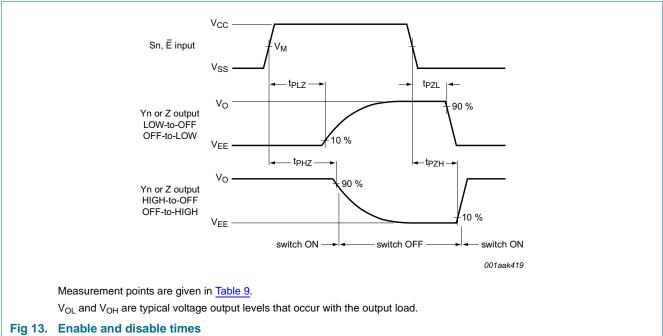


Table 9. **Measurement points**

| Supply voltage | Input | Output | Output | | | | | | |
|-----------------|--------------------|--------------------|-------------------------|-------------------------|--|--|--|--|--|
| V _{cc} | V _M | V _M | V _X | V _Y | | | | | |
| < 2.7 V | 0.5V _{CC} | 0.5V _{CC} | V_{OL} + 0.1 V_{CC} | $V_{OH} - 0.1 V_{CC}$ | | | | | |
| 2.7 V to 3.6 V | 1.5 V | 1.5 V | V _{OL} + 0.3 V | V _{OH} – 0.3 V | | | | | |
| > 3.6 V | 0.5V _{CC} | 0.5V _{CC} | V_{OL} + 0.1 V_{CC} | $V_{OH} - 0.1 V_{CC}$ | | | | | |

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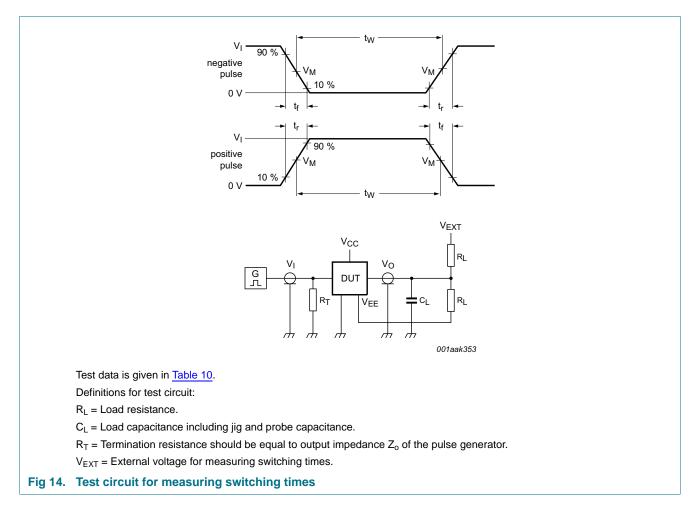


Table 10. Test data

| Supply voltage | Input | | Load | | V _{EXT} | | | |
|-----------------|-----------------|---------------------------------|--------------|------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| V _{cc} | VI | t _r , t _f | CL | RL | t _{PHL} , t _{PLH} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | |
| < 2.7 V | V _{CC} | ≤ 6 ns | 50 pF | 1 kΩ | open | V _{EE} | 2V _{CC} | |
| 2.7 V to 3.6 V | 2.7 V | ≤ 6 ns | 15 pF, 50 pF | 1 kΩ | open | V _{EE} | 2V _{CC} | |
| > 3.6 V | V _{CC} | ≤ 6 ns | 50 pF | 1 kΩ | open | V _{EE} | 2V _{CC} | |

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10.2 Additional dynamic parameters

Table 11. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 6.0$ ns; $T_{amb} = 25$ °C.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|------------------------------|--|-----|------|-----|------|
| THD | total harmonic distortion | $f_i = 1 \text{ kHz}; C_L = 50 \text{ pF}; R_L = 10 \text{ k}\Omega; \text{ see } \frac{\text{Figure } 19}{10 \text{ k}\Omega}$ | | | | |
| | | V _{CC} = 3.0 V; V _I = 2.75 V (p-p) | - | 0.8 | - | % |
| | | V _{CC} = 6.0 V; V _I = 5.5 V (p-p) | - | 0.4 | - | % |
| | | $f_i = 10 \text{ kHz}; C_L = 50 \text{ pF}; R_L = 10 \text{ k}\Omega; \text{ see } \frac{\text{Figure 19}}{10 \text{ km}}$ | | | | |
| | | V _{CC} = 3.0 V; V _I = 2.75 V (p-p) | - | 2.4 | - | % |
| | | V _{CC} = 6.0 V; V _I = 5.5 V (p-p) | - | 1.2 | - | % |
| f _(-3dB) | –3 dB frequency response | $C_L = 50 \text{ pF}; R_L = 50 \Omega; \text{ see } Figure 15$ | | | | |
| | | V _{CC} = 3.0 V | - | 180 | - | MHz |
| | | V _{CC} = 6.0 V | - | 200 | - | MHz |
| α_{iso} | isolation (OFF-state) | $f_i = 1 \text{ MHz}; C_L = 50 \text{ pF}; R_L = 600 \Omega; \text{ see Figure 17}$ | | | | |
| | | V _{CC} = 3.0 V | - | -50 | - | dB |
| | | V _{CC} = 6.0 V | - | -50 | - | dB |
| V _{ct} | crosstalk voltage | between digital inputs and switch; $f_i = 1 \text{ MHz}$; C _L = 50 pF; R _L = 600 Ω ; see Figure 20 | | | | |
| | | V _{CC} = 3.0 V | - | 0.11 | - | V |
| | | V _{CC} = 6.0 V | - | 0.12 | - | V |
| Xtalk | crosstalk | between switches; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 600 \Omega$; see Figure 21 | | | | |
| | | V _{CC} = 3.0 V | - | -60 | - | dB |
| | | V _{CC} = 6.0 V | - | -60 | - | dB |

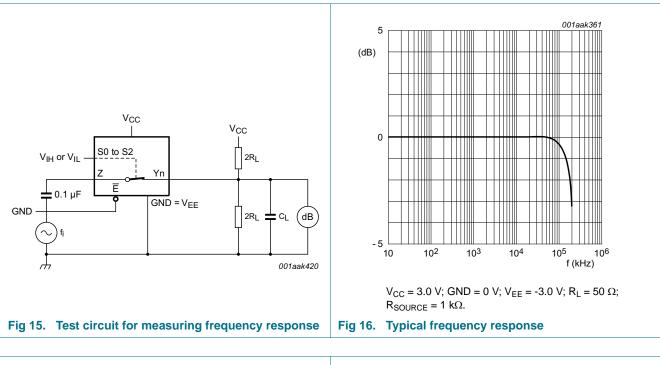
[1] Adjust f_i voltage to obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 50 Ω).

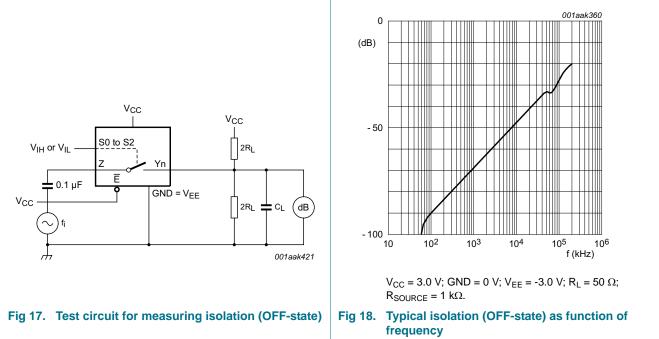
[2] Adjust f_i voltage to obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 600 Ω).

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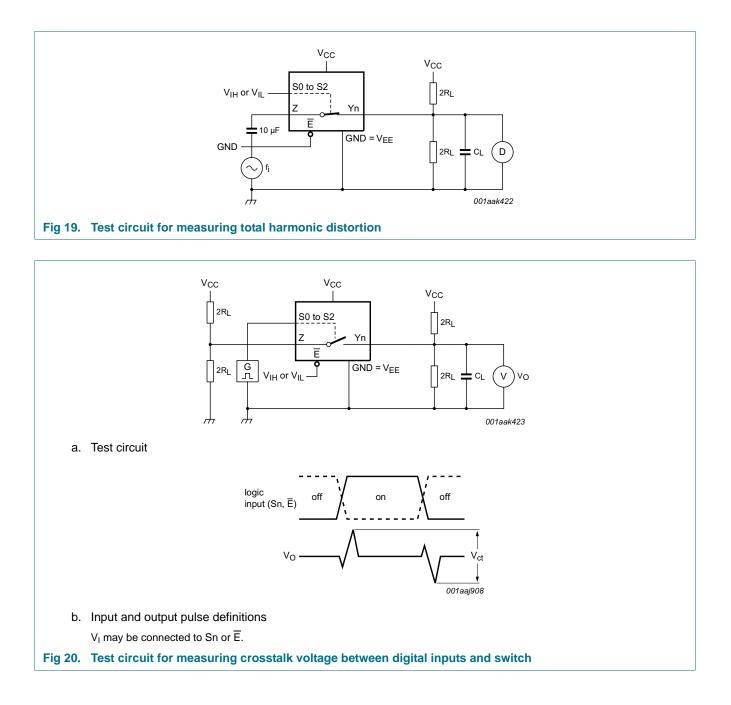


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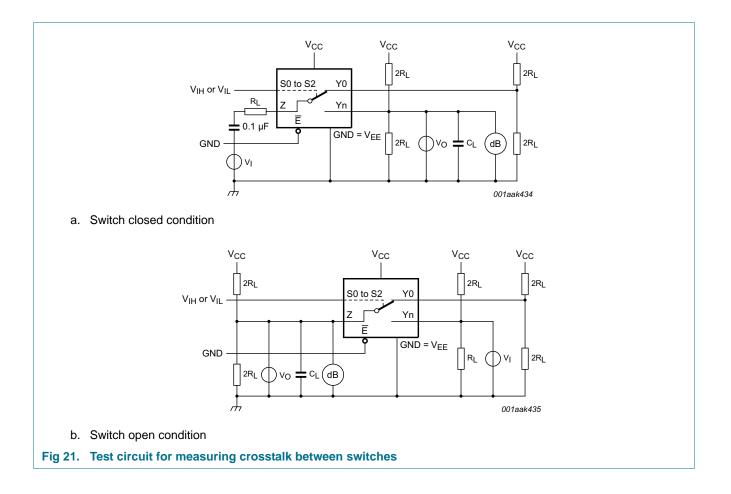
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11. Package outline

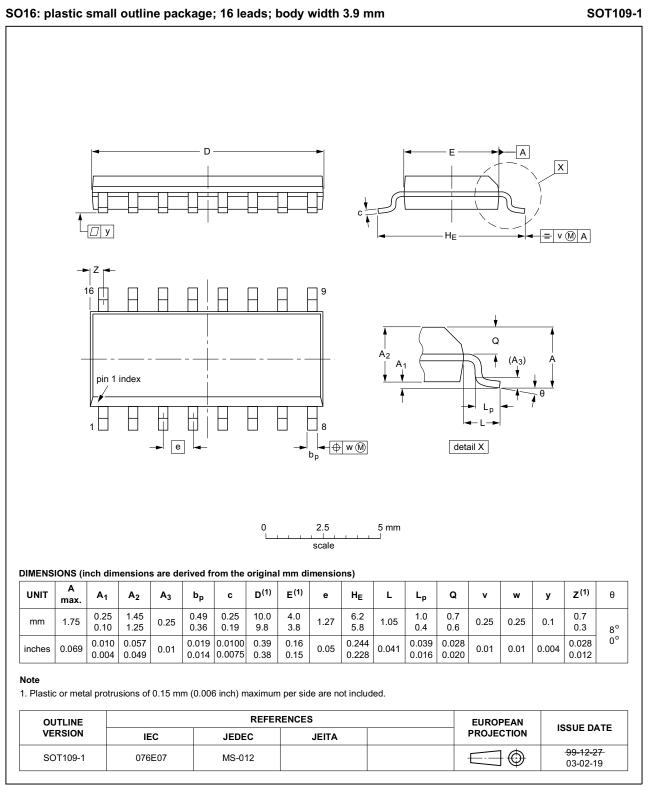


Fig 22. Package outline SOT109-1 (SO16)

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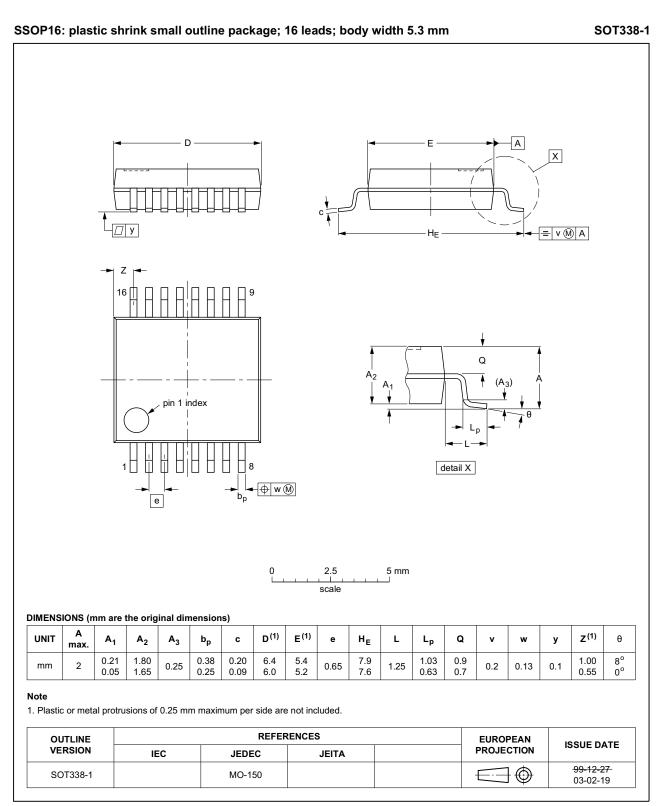


Fig 23. Package outline SOT338-1 (SSOP16)

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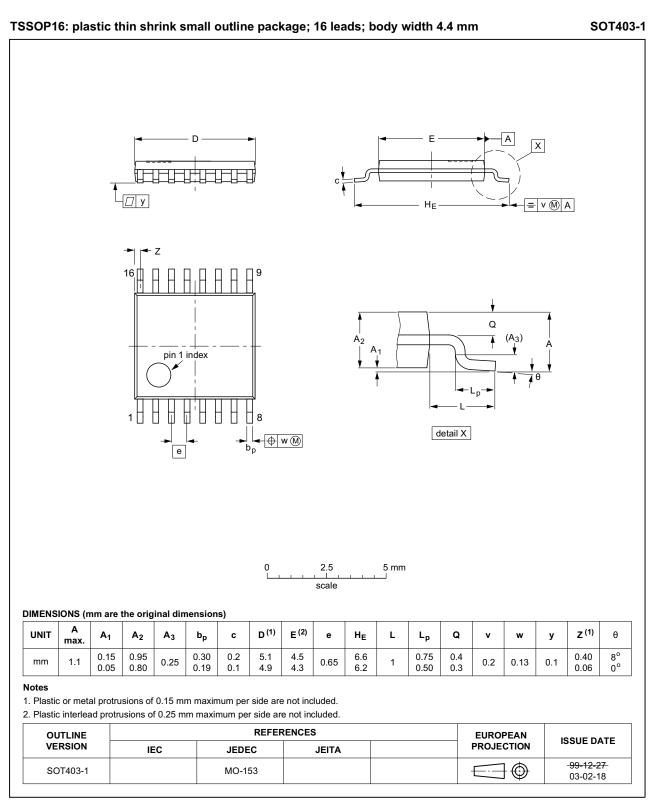
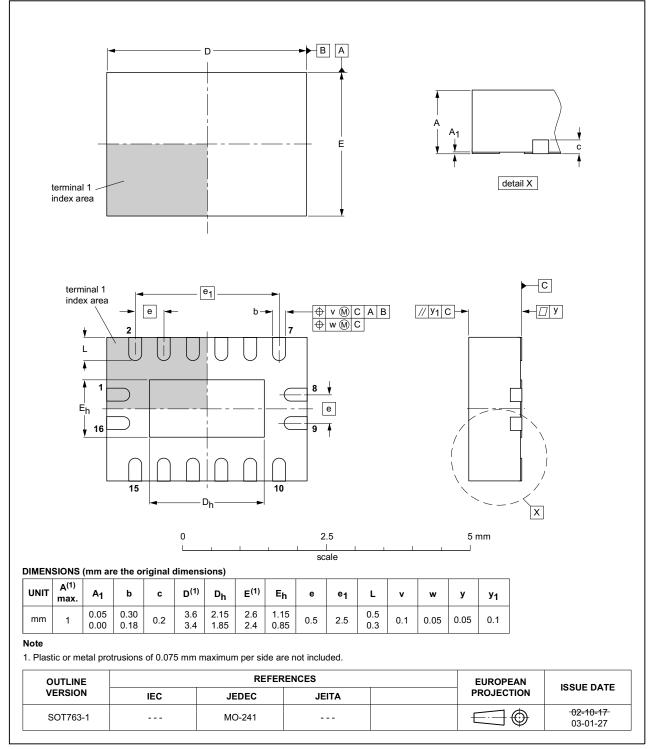


Fig 24. Package outline SOT403-1 (TSSOP16)

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

Fig 25. Package outline SOT763-1 (DHVQFN16)

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12. Abbreviations

| Table 12. Abbreviations | | |
|-------------------------|---|--|
| Acronym | Description | |
| CMOS | Complementary Metal-Oxide Semiconductor | |
| ESD | ElectroStatic Discharge | |
| НВМ | Human Body Model | |
| MM | Machine Model | |
| TTL | Transistor-Transistor Logic | |

13. Revision history

Table 13.Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---|--------------------------------------|----------------------------|---------------------|------------------------------------|
| 74LV4051 v.6 | 20160317 | Product data sheet | - | 74LV4051 v.5 |
| Modifications: | Type number | 74LV4051N (SOT38-4) re | moved. | |
| 74LV4051 v.5 | 20140917 | Product data sheet | - | 74LV4051 v.4 |
| Modifications: | • Figure 7: Figu | are note added for DHVQF | N16 package | |
| 74LV4051 v.4 | 20090810 | Product data sheet | - | 74LV4051 v.3 |
| Modifications: | The format of of NXP Semi | | redesigned to compl | y with the new identity guidelines |
| | Legal texts have | ave been adapted to the ne | ew company name w | /here appropriate. |
| Added type number 74LV4051BQ (DHVQFN16 package) | | | | |
| 74LV4051 v.3 | 19960623 | Product specification | - | 74LV4051 v.2 |
| 74LV4051 v.2 | 19970715 | Product specification | - | 74LV4051 v.1 |

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14. Legal information

14.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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